# Supporting information

# **Enhanced Sodium Ion Storage in MnO<sup>2</sup> through Asymmetric Orbital HybridizationsInduced**

# **by Spin-Paired Ion Doping**

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#### **Experimental Procedures**

### **Chemicals and reagents**

 $Mn(NO<sub>3</sub>)<sub>2</sub>$  and Tetramethylammonium hydroxide (TMA $\cdot$ OH) were obtained from Shanghai Macklin Biochemical Co., Ltd. SnCl<sub>4</sub>.5H<sub>2</sub>O was obtained from Innochem. H<sub>2</sub>O<sub>2</sub> was purchased from Beijing Chemical Works. Anhydrous (Na<sub>2</sub>SO<sub>4</sub>) was purchased from Beijing Tong Guang Fine Chemicals Company. All reagents were used as received without further purification. And all solutions were prepared using ultrapure water (resistance = 18.2 MΩ cm).

## **Characterization of the sample**

Microstructure were studied using scanning electron microscopy (SEM, FEI Quanta 200) at 20 kV, transmission electron microscopy (TEM; FEI Tecnai G2 20) and HRTEM (JEOL, JEM-2100, 200 kV). The electronic structure and compositional information on the samples were investigated by X-ray photoelectron spectroscopy (XPS, ESCALAB 250). The band gap of the materials were determined by UV-vis adsorption spectroscopy (Varian Cary 6000i) in the wavelength range of 250-800nm. JEOLJESFA200 EPR spectrometer was used to obtain the electron paramagnetic resonance (EPR) spectra, and operating parameters were 140K, 9064 MHz, 0.998 mW, X-band. The soft-XAS measurements were carried out in total electron yield mode under ultra-high vacuum at beamline 4B9B of Beijing Synchrotron Radiation Facility of the Institute of High Energy Physics, Chinese Academy of Sciences. Au  $4f_{7/2}$  core level spectra were recorded for the photon energy calibration, and the energy resolution is better than 0.2 eV at room temperature. The electrochemical operando Cell (EC-RAIR-H) is supplied by Beijing Science Star technology Co. Ltd. The Raman spectrum was recorded on a HORIBA Raman microscope with a laser wavelength of 532 nm (LabRAM Aramis, HORIBA Jobin Yvon S.A.S, France) for surface characterization. Raman spectra of the sample (one spectrum per 30 s) were captured while a cyclic voltammetry test at a scan rate of 2 mV s<sup>-1</sup> simultaneously.

## **Electrochemical measurements**

Working electrode was prepared by traditional slurry-coating method. 80 wt% active material, 10 wt% acetylene black and 10 wt% polytetrafluoroethylene (PTFE) was mixed and coated onto carbon cloth with an area of 1 cm<sup>2</sup>. The electrode was then heated at 60 °C for 2 hours to evaporate the solvent and used as working electrode. The negative electrode was prepared by mixing active carbon, acetylene black and PTFE with a mass ratio of 8:1:1. Electrochemical measurements were conducted in a general three-electrode configuration in 1.0

M Na<sub>2</sub>SO<sub>4</sub> aqueous electrolyte with Ag/AgCl and a Pt foil as reference electrode and counter electrode, respectively. Cyclic voltammetry (CV) and galvanostatic charge discharge (GCD) experiments were performed to determine the electrochemical properties of the electrodes in a potential window of -0.1 to 0.9 V. All the operating current densities were calculated based on the mass of the active materials Electrochemical impedance spectroscopy (EIS) measurements were carried out by applying an AC voltage with 5 mV amplitude in a frequency range from 0.01 Hz to 100 kHz at open potential.

The specific capacitance C (F  $g^{-1}$ ) was calculated based on the GCD curves according to equation <sup>1</sup>:

$$
C = \frac{I \times \Delta t}{m \times V}
$$
 (S1)

where I (A) and Δt (s) are the discharge current and time, respectively, m (g) represents of the active material's loading mass and V refers to the charge/discharge potential window.

## **Sodium diffusion coefficient calculation**

The diffusion coefficient of Na<sup>+</sup> (D<sub>Na</sub>+) can be obtained from the low frequency line according to the equation <sup>2</sup>:

$$
D_{Na}^{+} = 0.5(RT/AF^{2}C\sigma)^{2}
$$
 (S2)

where R, T, F, A, and C are the gas constant, the absolute temperature, the Faraday's constant, the apparent area of the electrode, and the molar concentration of Na<sup>+</sup>, respectively. σ is the Warburg factor following Equation:

$$
Z = Re + Rct + \sigma \omega^{-\frac{1}{2}}
$$
 (S3)

where  $R_e$  is the resistance between the electrolyte and electrode, and  $R_{ct}$  is the charge transfer resistance. Thus, the slopes of the plot of Z'vs  $ω^{-1/2}$  can used to obtain the values of σ.

# **Kinetic calculation**

Capacitance contribution can be qualitatively analysed according to CV curve, as shown below  $3$ :

$$
i = av^b
$$
 (S4)

where i and v are the current density and the potential scan rate, respectively,  $\alpha$  is a constant and b is a tunable parameter with a value of 0.5-1.0. When the value of b is close to 1.0, the reaction process is dominated by surface capacitance; when the value of b is close to 0.5, the reaction process is dominated by diffusion control.

The contribution of capacitance and diffusion limit to the total capacitance is further quantified  $4$ .

$$
i(V) = k_1 v + k_2 v^{1/2}
$$
 (S5)

where  $k_1$  and  $k_2$  represent capacitive and diffusion contributions, respectively. By determining both  $k_1$  and  $k_2$ , it is thus possible to distinguish the fraction of the current arising from Na<sup>+</sup> insertion and that from capacitive processes at specific potentials.

#### **Supercapacitor devices measurements**

Supercapacitor Devices Measurements: Asymmetric supercapacitor (ASC) device was fabricated by employing Sn-MnO<sub>2</sub> and AC as cathode and anode, respectively. Two electrodes were separated by glassy fibrous separator in 1 M Na<sub>2</sub>SO<sub>4</sub> aqueous electrolyte. Cyclic voltammetry (CV) and galvanostatic charge/discharge (GCD) measurements were performed in a potential window of -0.1 to 0.9 V.

The energy density (E, Wh kg<sup>-1</sup>) of the ASC is calculated according to S6<sup>5</sup>:

$$
E = \frac{C \times V^2}{2} \times \frac{1000}{3600}
$$
 (56)

The power density (P, W kg<sup>-1</sup>) of the ASC is calculated according to S7<sup>6</sup>:

$$
P = \frac{E \times 3600}{t}
$$
 (S7)

where t (s) is discharge time.

## **DFT Methods**

We have employed the Vienna Ab initio Simulation Package (VASP) to perform all density functional theory (DFT) calculations within spin-polarized frame. The elemental core and valence electrons were represented by the projector augmented wave (PAW) method and plane-wave basis functions with a cutoff energy of 520 eV. Generalized gradient approximation with the Perdew-Burke-Ernzerhof (GGA-PBE) exchange-correlation functional was employed in all the calculations. The DFT-D3 empirical correction method was employed to describe van der Waals interactions. Geometry optimizations were performed with the force convergency smaller than 0.07 eV/Å. Monkhorst-Pack k-points of 1×1×1 was applied for all the calculations. To overcome this shortcoming, the GGA+U approach was used with U-J = 3.9 eV for the Mn atoms.

# **Supporting figures**



Fig. S1 (a) SEM image and (b) TEM image of  $MnO_2$ , (c) SAED image of  $MnO_2$ .



**Fig. S2** XPS spectra: O 1s of  $Sn-MnO<sub>2</sub>$  and  $MnO<sub>2</sub>$ .



**Fig. S3** (a, b) CV curves of Sn-MnO<sub>2</sub> and MnO<sub>2</sub> samples at different scan rates from 5-200 mV s<sup>-1</sup>. (c) GCD curves at different current densities of  $MnO<sub>2</sub>$  sample.



**Fig. S4** (a) CV curves of MnO<sub>2</sub> at different scan from 1-6 mV s<sup>-1</sup>. (b) The linear fitting curves of log (i) versus log (v) according to the CV results in (a). (c) Diffusion contributions and capacitive contributions of  $MnO_2$ .



Fig. S5 Pseudocapacitive fraction (shown by the shaded area) calculated at a scan rate of 1-6 mV s<sup>-1</sup> from CV curves at different scan rates of (a, b, c, d, e, f) Sn-MnO<sub>2</sub> electrode.



Fig. S6 Pseudocapacitive fraction (shown by the shaded area) calculated at a scan rate of 1-6 mV s<sup>-1</sup> from CV curves at different scan rates of (a, b, c, d, e, f)  $MnO<sub>2</sub>$  electrode.



**Fig. S7** Diagram of Z' and ω−1/2 in the low frequency zone obtained from EIS measurement and the calculated diffusion coefficient of  $Sn-MnO<sub>2</sub>$  and  $MnO<sub>2</sub>$ .



**Fig. S8** (a, b) Cycling stability of Sn-MnO<sub>2</sub> electrode and MnO<sub>2</sub> electrode at a current density of 1 A g<sup>-1</sup>.



**Fig. S9**. HRTEM images of cycled MnO<sub>2</sub> and Sn-MnO<sub>2</sub> cathode materials.



Fig. S10. Ex-situ XRD patterns of MnO<sub>2</sub> and Sn-MnO<sub>2</sub>.



**Fig. S11**. The assembled prototype of the supercapacitor.



**Fig. S12** The top view (above) and side view (below) of optimized structure for (a) undoped Sn-MnO<sub>2</sub> and (b) MnO<sub>2</sub>. Color codes: Mn, purple; O, pink; Sn, grey, respectively.

# **References**

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